



Pages 1 to 28

**INTEGRATED CIRCUITS, SILICON MONOLITHIC, CMOS
ANALOGUE MULTIPLEXER/DEMULTIPLEXER
(SINGLE 8-CHANNEL)**

BASED ON TYPE 4051B

ESCC Detail Specification No. 9202/047

Issue 2	June 2004
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Document Custodian: European Space Agency - see <https://escies.org>

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DCR No.	CHANGE DESCRIPTION
85, 90	Specification up issued to incorporate editorial and technical changes per DCR.

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1. GENERAL

1.1 SCOPE

This specification details the ratings, physical and electrical characteristics and test and inspection data for the component type variants and/or the range of components specified below. It supplements the requirements of, and shall be read in conjunction with, the ESCC Generic Specification listed under Applicable Documents.

1.2 APPLICABLE DOCUMENTS

The following documents form part of this specification and shall be read in conjunction with it:

- (a) ESCC Generic Specification No. 9000
- (b) MIL-STD-883, Test Methods and Procedures for Microelectronics

1.3 TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESCC Basic Specification No. 21300 shall apply.

1.4 THE ESCC COMPONENT NUMBER AND COMPONENT TYPE VARIANTS

1.4.1 The ESCC Component Number

The ESCC Component Number shall be constituted as follows:

Example: 920204701

- Detail Specification Reference: 9202047
- Component Type Variant Number: 01 (as required)

1.4.2 Component Type Variants

The component type variants applicable to this specification are as follows:

Variant Number	Based on Type	Case	Terminal Material and /or Finish	Weight max g
01	4051B	FP	G2	0.7
02	4051B	FP	G4	0.7
07	4051B	CCP	2	0.6
08	4051B	DIP	G2	2.2
09	4051B	DIP	G4	2.2
10	4051B	SO	G2	0.7
11	4051B	SO	G4	0.7

The terminal material and/or finish shall be in accordance with the requirements of ESCC Basic Specification No. 23500.

1.5 **MAXIMUM RATINGS**

The maximum ratings shall not be exceeded at any time during use or storage.

Maximum ratings shall only be exceeded during testing to the extent specified in this specification and when stipulated in Test Methods and Procedures of the ESCC Generic Specification.

Characteristics	Symbols	Maximum Ratings	Units	Remarks
Supply Voltage	V_{DD}	-0.5 to 18	V	Note 1
Supply Voltage Range	$V_{DD}-V_{EE}$	-0.5 to 18	V	Note 2
Control Input Voltage	V_{IN}	-0.5 to $V_{DD} +0.5$	V	Note 1 Power on
Channel Input/Output Voltage	V_{IN}	$V_{EE} -0.5$ to $V_{DD} +0.5$	V	Note 1, 3
Control Input Current	I_{IN}	± 10	mA	-
Device Power Dissipation (Continuous)	P_D	200	mW	-
Power Dissipation per Single Output	P_{DSO}	100	mW	-
Operating Temperature Range	T_{op}	-55 to +125	$^{\circ}C$	T_{amb}
Storage Temperature Range	T_{stg}	-65 to +150	$^{\circ}C$	-
Soldering Temperature For FP, DIP and SO For CCP	T_{sol}	+265 +245	$^{\circ}C$	Note 4 Note 5

NOTES:

1. Device is functional for $3V \leq V_{DD} \leq 15V$ with reference to V_{SS} .
2. Device is functional for $3V \leq V_{DD}-V_{EE} \leq 15V$.
3. To avoid draining V_{DD} supply current into the ON Channel when current flows from CHn to COM the voltage drop across the ON Channel shall not exceed 0.4V.
4. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same terminal shall not be resoldered until 3 minutes have elapsed.
5. Duration 5 seconds maximum and the same terminal shall not be resoldered until 3 minutes have elapsed.

1.6 **HANDLING PRECAUTIONS**

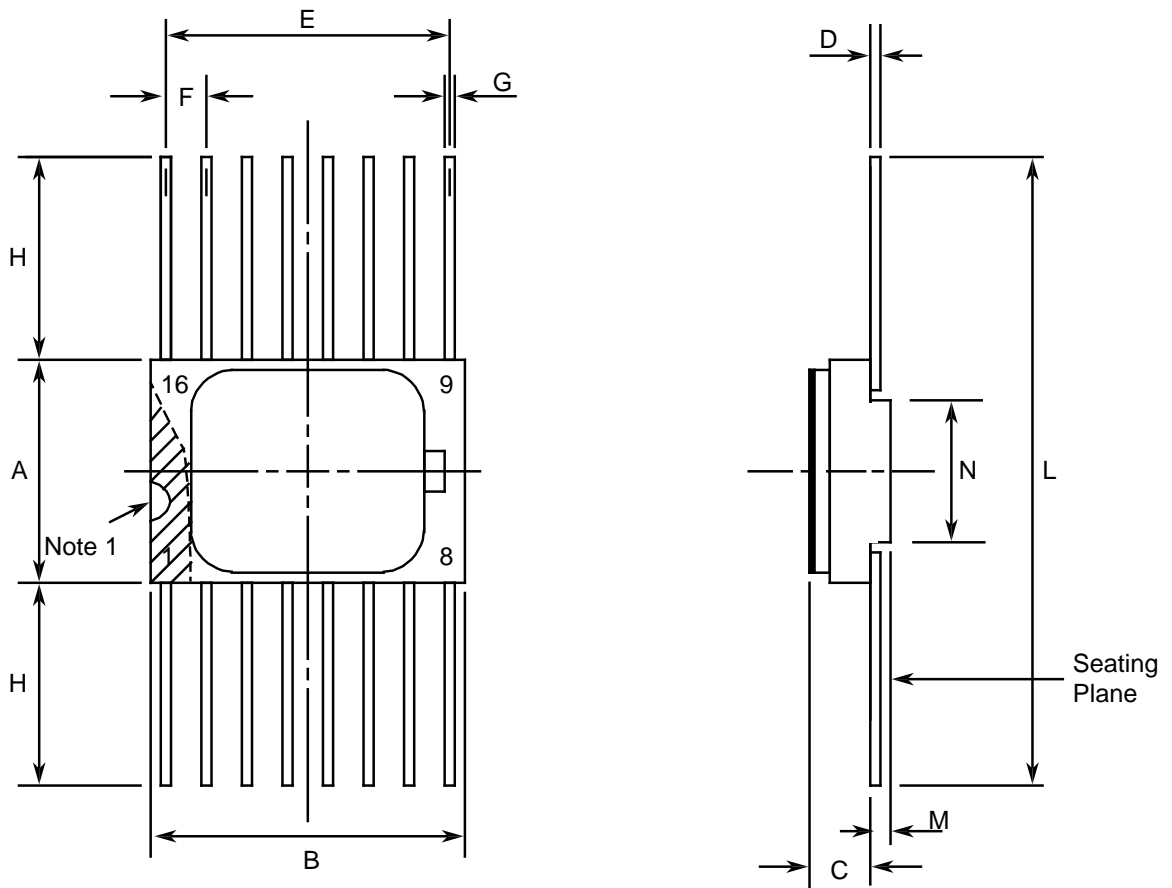
These devices are susceptible to damage by electrostatic discharge. Therefore, suitable precautions shall be employed for protection during all phases of manufacture, testing, packaging, shipment and any handling.

These components are categorised as Class 1 per ESCC Basic Specification No. 23800 with a minimum Critical Path Failure Voltage of 400 Volts.

1.7 **PHYSICAL DIMENSIONS AND TERMINAL IDENTIFICATION**

Consolidated Notes are given following the case drawings and dimensions.

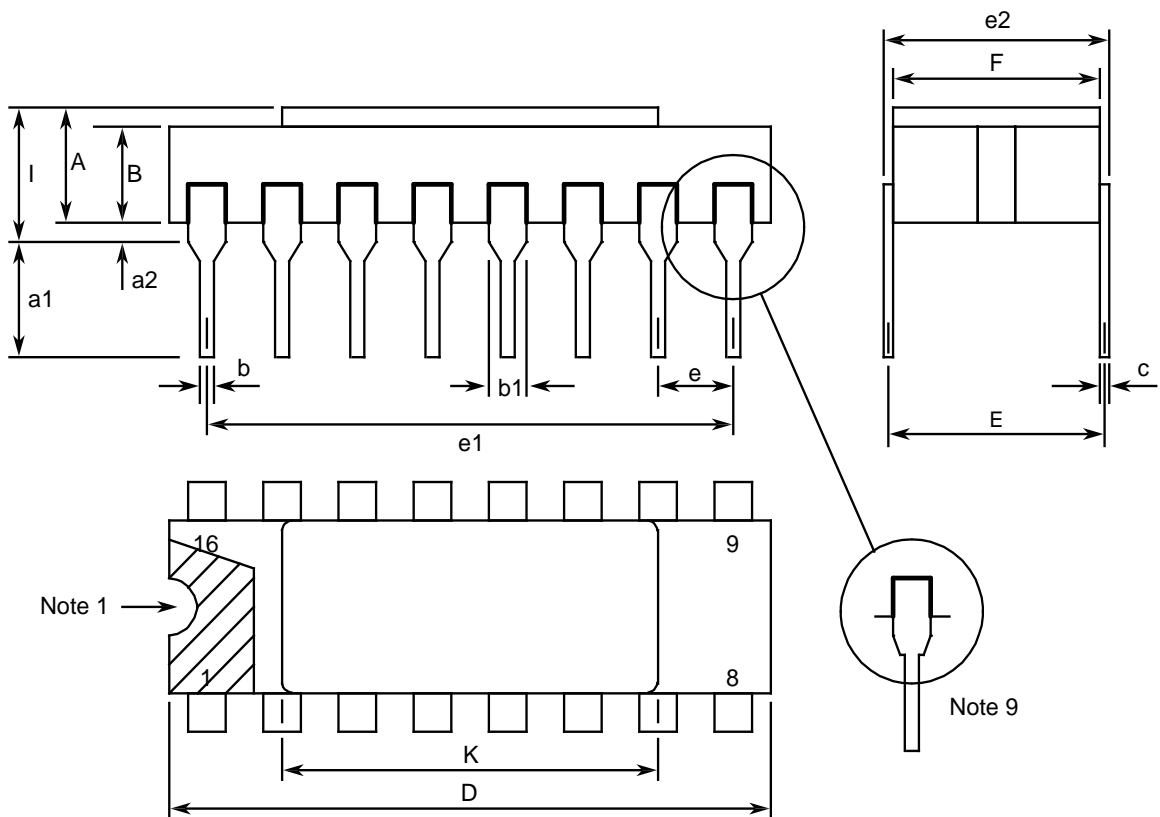
1.7.1 **Flat Package (FP) - 16 Pin**



Symbols	Dimensions mm		Notes
	Min	Max	
A	6.75	7.06	
B	9.76	10.14	
C	1.49	1.95	
D	0.1	0.15	5
E	8.76	9.01	
F	1.27 TYPICAL		3, 6
G	0.38	0.48	5
H	6	-	5
L	18.75	22	
M	0.33	0.43	

Symbols	Dimensions mm		Notes
	Min	Max	
N	4.32 TYPICAL		

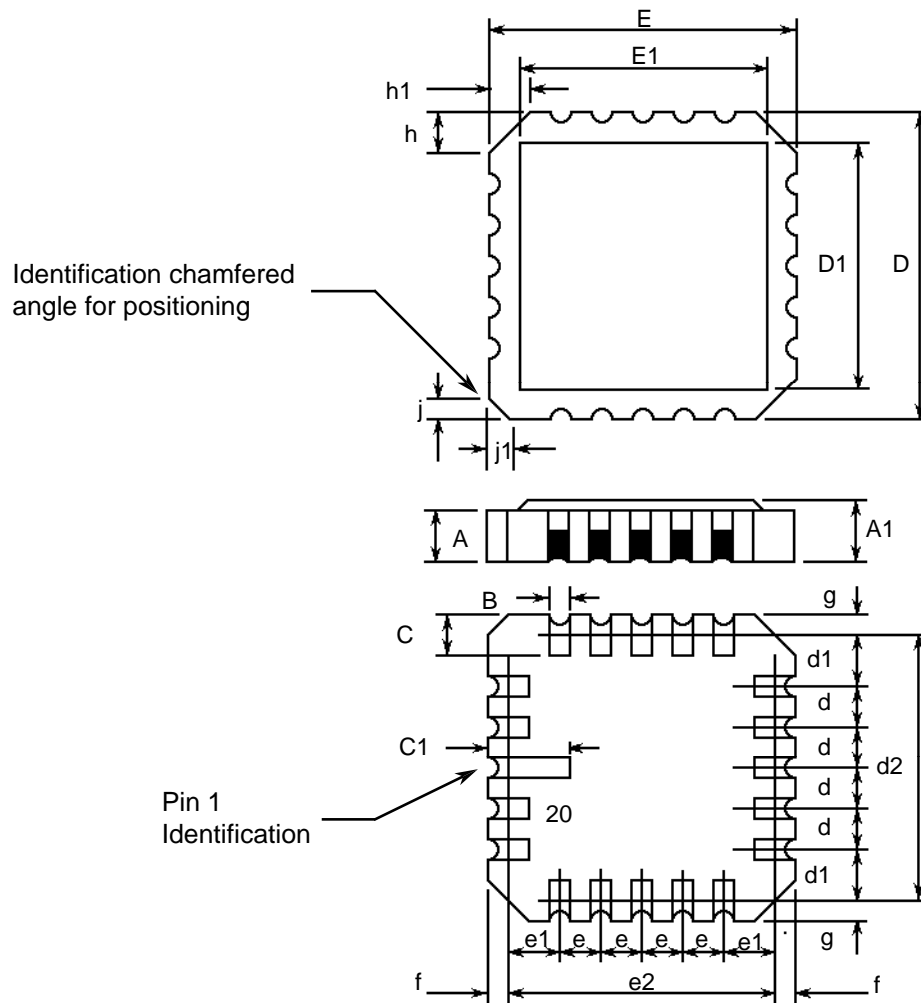
1.7.2 Dual-in-line Package (DIP) - 16 Pin



Symbols	Dimensions mm		Notes
	Min	Max	
A	2.1	2.71	
a1	3	3.7	
a2	0.63	1.14	2
B	1.82	2.39	
b	0.4	0.5	5
b1	1.14	1.5	5
c	0.2	0.3	5
D	20.06	20.58	
E	7.36	7.87	

Symbols	Dimensions mm		Notes
	Min	Max	
e	2.54 TYPICAL		4, 6
e1	17.65	17.9	
e2	7.62	8.12	
F	7.29	7.7	
l	-	3.83	
K	10.9	12.1	

1.7.3 Chip Carrier Package (CCP) - 20 Terminal



Symbols	Dimensions mm		Notes
	Min	Max	
A	1.14	1.95	
A1	1.63	2.36	
B	0.55	0.72	5
C	1.06	1.47	5
C1	1.91	2.41	
D	8.67	9.09	
D1	7.21	7.52	
d, d1	1.27 TYPICAL		3, 6
d2	7.62 TYPICAL		
E	8.67	9.09	
E1	7.21	7.52	
e, e1	1.27 TYPICAL		3, 6
e2	7.62 TYPICAL		
f, g	-	0.76	
h, h1	1.01 TYPICAL		8
j, j1	0.51 TYPICAL		7

1.7.4 Small Outline Ceramic Package (SO) - 16 Pin



Symbols	Dimensions mm		Notes
	Min	Max	
A	6.75	7.06	
B	9.76	10.14	
C	1.49	1.95	
D	0.1	0.15	5
E	8.76	9.01	
F	1.27 TYPICAL		3, 6
G	0.38	0.48	5
H	0.6	0.9	5

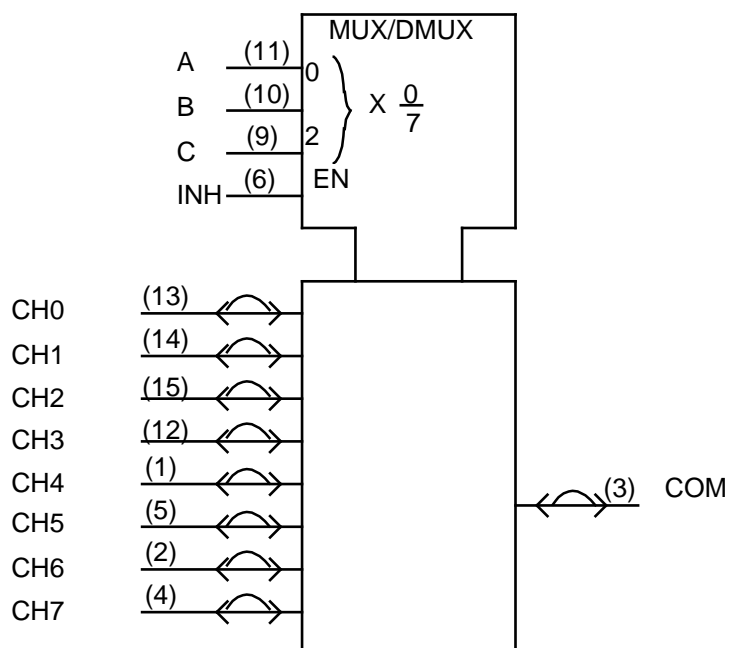
Symbols	Dimensions mm		Notes
	Min	Max	
K	9 TYPICAL		
L	10	10.65	
M	0.33	0.43	
N	4.31 TYPICAL		

1.7.5 Consolidated Notes

1. Index area; a notch or a dot shall be located adjacent to Pin 1 and shall be within the shaded area shown. For chip carrier packages, the index shall be as shown.
2. The dimension shall be measured from the seating plane to the base plane.
3. The true position pin spacing is 1.27mm between centrelines. Each pin centreline shall be located within $\pm 0.13\text{mm}$ of its true longitudinal position relative to Pin 1 and the highest pin number.
4. The true position pin spacing is 2.54mm between centrelines. Each pin centreline shall be located within $\pm 0.25\text{mm}$ of its true longitudinal position relative to Pin 1 and the highest pin number.
5. All terminals.
6. 14 spaces for flat, dual-in-line and small outline packages.
16 spaces for chip carrier packages.
7. Index corner only - 2 dimensions.
8. 3 non-index corners - 6 dimensions.
9. For all pins, either pin shape may be supplied.

1.8 FUNCTIONAL DIAGRAM

Pin numbers relate to FP, DIP and SO packages only.



1.9 PIN ASSIGNMENT

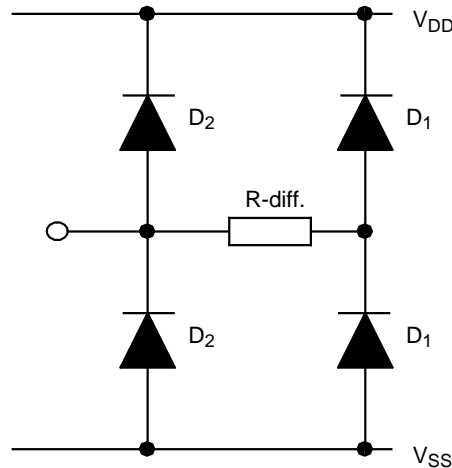
Pin	Function		Pin	Function	
	FP, DIP and SO	CCP		FP, DIP and SO	CCP
1	CH4 Input/Output (Channel)	CH4 Input/Output (Channel)	11	A Input (Select)	C Input (Select)
2	CH6 Input/Output (Channel)	CH6 Input/Output (Channel)	12	CH3 Input/Output (Channel)	B Input (Select)
3	COM Output/Input (Common)	-	13	CH0 Input/Output (Channel)	-
4	CH7 Input/Output (Channel)	COM Output/Input (Common)	14	CH1 Input/Output (Channel)	A Input (Select)
5	CH5 Input/Output (Channel)	CH7 Input/Output (Channel)	15	CH2 Input/Output (Channel)	CH3 Input/Output (Channel)
6	INH Input (Inhibit)	CH5 Input/Output (Channel)	16	V _{DD}	CH0 Input/Output (Channel)
7	V _{EE} (Analogue Negative Supply)	INH Input (Inhibit)	17	-	CH1 Input/Output (Channel)
8	V _{SS} (Digital Negative Supply)	-	18	-	-
9	C Input (Select)	V _{EE} (Analogue Negative Supply)	19	-	CH2 Input/Output (Channel)
10	B Input (Select)	V _{SS} (Digital Negative Supply)	20	-	V _{DD}

1.10 TRUTH TABLE

1. Logic Level Definitions: L = Low Level, H = High Level, X =Irrelevant.

CONTROL INPUTS				ON CHANNEL
INH	SELECT			
	C	B	A	
L	L	L	L	0 (CH0 to COM, COM to CH0)
L	L	L	H	1 (CH1 to COM, COM to CH1)
L	L	H	L	2 (CH2 to COM, COM to CH2)
L	L	H	H	3 (CH3 to COM, COM to CH3)
L	H	L	L	4 (CH4 to COM, COM to CH4)
L	H	L	H	5 (CH5 to COM, COM to CH5)
L	H	H	L	6 (CH6 to COM, COM to CH6)
L	H	H	H	7 (CH7 to COM, COM to CH7)
H	X	X	X	NONE (High Impedance)

1.11 INPUT PROTECTION NETWORK (CONTROL INPUTS)



2. REQUIREMENTS

2.1 GENERAL

The complete requirements for procurement of the components specified herein are as stated in this specification and the ESCC Generic Specification. Permitted deviations from the Generic Specification, applicable to this specification only, are listed below.

Permitted deviations from the Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESCC requirement and do not affect the component's reliability, are listed in the appendices attached to this specification.

2.1.1 Deviations from the Generic Specification

None.

2.2 MARKING

The marking shall be in accordance with the requirements of ESCC Basic Specification No. 21700 and as follows.

The information to be marked on the component shall be:

- (a) Terminal identification.
- (b) The ESCC qualified components symbol (for ESCC qualified components only).
- (c) The ESCC Component Number.
- (d) Traceability information.

2.3 ELECTRICAL MEASUREMENTS AT ROOM, HIGH AND LOW TEMPERATURES

Electrical measurements shall be performed at room, high and low temperatures. Consolidated Notes

are given after the tables.

2.3.1 Room Temperature Electrical Measurements

The measurements shall be performed at $T_{amb}=+22 \pm 3^{\circ}C$.

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Functional Test 1	-	3014	Verify Truth Table $V_{IL}=0V, V_{IH}=3V$ $V_{DD}=3V, V_{SS}=V_{EE}=0V$ Note 2	-	-	-
Functional Test 2	-	3014	Verify Truth Table $V_{IL}=0V, V_{IH}=15V$ $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$ Note 2	-	-	-
Quiescent Current	I_{DD}	3005	$V_{IL}=0V, V_{IH}=15V$ $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$ Note 3	-	500	nA
Low Level Input Current, Control Inputs	I_{IL}	3009	V_{IN} (Under Test)=0V $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$	-	-50	nA
High Level Input Current, Control Inputs	I_{IH}	3010	V_{IN} (Under Test)=15V $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$	-	50	nA
Channel OFF Leakage Current 1, Any Channel CHn	I_{OFF1}	-	Channel Under Test V_{IN} (CH)=15V V_{IN} (COM)=0V All other Channels Open $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$	-	-100	nA
Channel OFF Leakage Current 2, Any Channel CHn	I_{OFF2}	-	Channel Under Test V_{IN} (CH)=0V V_{IN} (COM)=15V All other Channels Open $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$	-	100	nA
Channel OFF Leakage Current 3, All Channels Tested Together	I_{OFF3}	-	V_{IN} (CH)=0V V_{IN} (COM)=15V $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$	-	100	nA

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Channel OFF Leakage Current 4, All Channels Tested Together	I_{OFF4}	-	$V_{IN} (CH)=15V$ $V_{IN} (COM)=0V$ $V_{DD}=15V,$ $V_{SS}=V_{EE}= 0V$	-	-100	nA
Channel ON Resistance 1	R_{ON1}	-	$V_{IL}=0V, V_{IH}=5V$ $R_L=10k\Omega$ $V_{DD}=5V, V_{SS}=V_{EE}= 0V$ Note 4	-	1050	Ω
Channel ON Resistance 2	R_{ON2}	-	$V_{IL}=0V, V_{IH}=15V$ $R_L=10k\Omega$ $V_{DD}=15V,$ $V_{SS}=V_{EE}= 0V$ Note 4	-	280	Ω
Low Level Input Voltage 1 (Noise Immunity) (Functional Test)	V_{IL1}	-	Verify Truth Table $V_{DD}=5V, V_{SS}=V_{EE}=0V$ Note 5	-	1.5	V
Low Level Input Voltage 2 (Noise Immunity) (Functional Test)	V_{IL2}	-	Verify Truth Table $V_{DD}=15V,$ $V_{SS}=V_{EE}= 0V$ Note 5	-	4	V
High Level Input Voltage 1 (Noise Immunity) (Functional Test)	V_{IH1}	-	Verify Truth Table $V_{DD}=5V, V_{SS}=V_{EE}=0V$ Note 5	3.5	-	V
High Level Input Voltage 2 (Noise Immunity) (Functional Test)	V_{IH2}	-	Verify Truth Table $V_{DD}=15V,$ $V_{SS}=V_{EE}= 0V$ Note 5	11	-	V
Threshold Voltage N-Channel	V_{THN}	-	INH Input and V_{EE} at Ground All Other Inputs: $V_{IN}=5V$ $V_{DD}=5V, I_{SS}=-10\mu A$	-0.7	-3	V
Threshold Voltage P-Channel	V_{THP}	-	INH Input at Ground All Other Inputs: $V_{IN}=-5V$ $V_{SS}=V_{EE}=-5V,$ $I_{DD}=3.5\mu A$	0.7	3	V
Input Clamp Voltage 1, to V_{SS} , Control Inputs	V_{IC1}	-	$I_{IN} (Under Test)=-100\mu A$ $V_{DD}=Open, V_{SS}=0V$ All Other Pins Open	-	-2	V

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Input Clamp Voltage 2, to V_{DD} , Control Inputs	V_{IC2}	-	V_{IN} (Under Test)=6V $R=30k\Omega$, $V_{SS}=Open$ All Other Pins Open Note 6	3	-	V
Input Capacitance, Control Inputs	C_{IN}	3012	V_{IN} (Not Under Test)=0V $V_{DD}=V_{SS}=V_{EE}=0V$ $f = 100\text{ kHz to }1\text{ MHz}$ Note 7	-	7.5	pF
Channel Capacitance, CHn	C_{CH}	3012	V_{IN} (Not Under Test)=0V $V_{DD}=V_{SS}=V_{EE}=0V$ $f = 100\text{ kHz to }1\text{ MHz}$ Note 7	-	7.5	pF
Channel Capacitance, COM	C_{COM}	3012	V_{IN} (Not Under Test)=0V $V_{DD}=V_{SS}=V_{EE}=0V$ $f = 100\text{ kHz to }1\text{ MHz}$ Note 7	-	7.5	pF
Propagation Delay Low to High 1, COM to CH0	t_{PLH1}	3003	$V_{IN}(COM)=Pulse$ Generator V_{IN} (Remaining Inputs)=Truth Table $V_{IL}=0V$, $V_{IH}=5V$, $R_L=200k\Omega$ $V_{DD}=5V$, $V_{SS}=V_{EE}=0V$ Note 8	-	40	ns
Propagation Delay High to Low 1, COM to CH0	t_{PHL1}	3003	$V_{IN}(COM)=Pulse$ Generator V_{IN} (Remaining Inputs)=Truth Table $V_{IL}=0V$, $V_{IH}=5V$, $R_L=200k\Omega$ $V_{DD}=5V$, $V_{SS}=V_{EE}=0V$ Note 8	-	40	ns
Propagation Delay Low to High 2, A to COM (Channel ON)	t_{PLH2}	3003	$V_{IN}(A)=Pulse$ Generator V_{IN} (Remaining Inputs)=Truth Table $V_{IL}=0V$, $V_{IH}=5V$, $V_{IN}(CH)=0V$ and 5V $R_L=10k\Omega$ $V_{DD}=5V$, $V_{SS}=V_{EE}=0V$ Note 8	-	670	ns

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Propagation Delay High to Low 2, A to COM (Channel ON)	t_{PHL2}	3003	$V_{IN}(A)=$ Pulse Generator V_{IN} (Remaining Inputs)=Truth Table $V_{IL}=0V, V_{IH}=5V,$ $V_{IN}(CH)=0V$ and $5V$ $R_L=10k\Omega$ $V_{DD}=5V, V_{SS}=V_{EE}=0V$ Note 8	-	670	ns
Output Enable Time High Impedance to High Output, INH to COM	t_{PZH}	3003	$V_{IN}(INH)=$ Pulse Generator V_{IN} (Remaining Inputs)=Truth Table $V_{IL}=0V, V_{IH}=5V,$ $V_{IN}(CH)=5V, R_L=10k\Omega$ $V_{DD}=5V, V_{SS}=V_{EE}=0V$ Note 8	-	400	ns
Output Disable Time High Output to High Impedance, INH to COM	t_{PHZ}	3003	$V_{IN}(INH)=$ Pulse Generator V_{IN} (Remaining Inputs)=Truth Table $V_{IL}=0V, V_{IH}=5V,$ $V_{IN}(CH)=5V, R_L=300\Omega$ $V_{DD}=5V, V_{SS}=V_{EE}=0V$ Note 8	-	400	ns

2.3.2 High and Low Temperatures Electrical Measurements

The measurements shall be performed at $T_{amb}=+125 (+0 -5) ^\circ C$ and $T_{amb}=- 55(+5-0)^\circ C$.

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Functional Test 1	-	3014	Verify Truth Table $V_{IL}=0V, V_{IH}=3V$ $V_{DD}=3V,$ $V_{SS}=V_{EE}=0V$ Note 2	-	-	-
Functional Test 2	-	3014	Verify Truth Table $V_{IL}=0V, V_{IH}=15V$ $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$ Note 2	-	-	-
Quiescent Current	I_{DD}	3005	$V_{IL}=0V, V_{IH}=15V$ $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$ Note 3 $T_{amb}=+125^\circ C$ $T_{amb}=- 55^\circ C$	-	15	μA
				-	0.5	

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Low Level Input Current, Control Inputs	I_{IL}	3009	V_{IN} (Under Test)=0V $V_{DD}=15V$, $V_{SS}=V_{EE}=0V$ $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	- -	-100 -50	nA
High Level Input Current, Control Inputs	I_{IH}	3010	V_{IN} (Under Test)=15V $V_{DD}=15V$, $V_{SS}=V_{EE}=0V$ $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	- -	100 50	nA
Channel OFF Leakage Current 1, Any Channel CHn	I_{OFF1}	-	Channel Under Test V_{IN} (CH)=15V V_{IN} (COM)=0V All other Channels Open $V_{DD}=15V$, $V_{SS}=V_{EE}=0V$ $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	- -	-1 -0.1	μA
Channel OFF Leakage Current 2, Any Channel CHn	I_{OFF2}	-	Channel Under Test V_{IN} (CH)=0V V_{IN} (COM)=15V All other Channels Open $V_{DD}=15V$, $V_{SS}=V_{EE}=0V$ $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	- -	1 0.1	μA
Channel OFF Leakage Current 3, All Channels Tested Together	I_{OFF3}	-	V_{IN} (CH)=0V V_{IN} (COM)=15V $V_{DD}=15V$, $V_{SS}=V_{EE}=0V$ $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	- -	1 0.1	μA
Channel OFF Leakage Current 4, All Channel Tested Together	I_{OFF4}	-	V_{IN} (CH)=15V V_{IN} (COM)=0V $V_{DD}=15V$, $V_{SS}=V_{EE}=0V$ $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	- -	-1 -0.1	μA
Channel ON Resistance 1	R_{ON1}	-	$V_{IL}=0V$, $V_{IH}=5V$ $R_L=10k\Omega$ $V_{DD}=5V$, $V_{SS}=V_{EE}=0V$ Note 4 $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	- -	1200 880	Ω

Characteristics	Symbols	MIL-STD-883 Test Method	Test Conditions Note 1	Limits		Units
				Min	Max	
Channel ON Resistance 2	R_{ON2}	-	$V_{IL}=0V, V_{IH}=15V$ $R_L=10k\Omega$ $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$ Note 4 $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	- -	400 220	Ω
Low Level Input Voltage 1 (Noise Immunity) (Functional Test)	V_{IL1}	-	Verify Truth Table $V_{DD}=5V, V_{SS}=V_{EE}=0V$ Note 5	-	1.5	V
Low Level Input Voltage 2 (Noise Immunity) (Functional Test)	V_{IL2}	-	Verify Truth Table $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$ Note 5	-	4	V
High Level Input Voltage 1 (Noise Immunity) (Functional Test)	V_{IH1}	-	Verify Truth Table $V_{DD}=5V, V_{SS}=V_{EE}=0V$ Note 5	3.5	-	V
High Level Input Voltage 2 (Noise Immunity) (Functional Test)	V_{IH2}	-	Verify Truth Table $V_{DD}=15V,$ $V_{SS}=V_{EE}=0V$ Note 5	11	-	V
Threshold Voltage N-Channel	V_{THN}	-	INH Input and V_{EE} at Ground All Other Inputs: $V_{IN}=5V$ $V_{DD}=5V, I_{SS}=-10\mu A$ $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	-0.3 -0.7	-3.5 -3.5	V
Threshold Voltage P-Channel	V_{THP}	-	INH Input at Ground All Other Inputs: $V_{IN}=-5V$ $V_{SS}=V_{EE}=-5V,$ $I_{DD}=3.5\mu A$ $T_{amb}=+125^{\circ}C$ $T_{amb}=-55^{\circ}C$	0.3 0.7	3.5 3.5	V

2.3.3

Notes to Electrical Measurement Tables

1. Unless otherwise specified all inputs and channels shall be tested for each characteristic, inputs not under test shall be $V_{IN} = V_{SS}$ or V_{DD} and channels not under test shall be open.
2. Functional tests shall be performed to verify Truth Table. The Maximum time to output comparator strobe = 300 μ s.
3. Quiescent Current shall be tested using the following input conditions where 1 = V_{IH} and 0 = V_{IL} :

TEST	INPUT CONDITIONS												
	INH	A	B	C	COM	CH0	CH1	CH2	CH3	CH4	CH5	CH6	CH7
(a)	0	0	0	0	1	1	1	1	1	1	1	1	1
(b)	0	1	1	0	1	1	1	1	1	1	1	1	1
(c)	0	0	0	0	1	1	1	1	1	1	1	1	1
(d)	0	1	1	0	0	0	0	0	0	0	0	0	0
(e)	0	0	0	1	1	1	1	1	1	1	1	1	1
(f)	0	1	1	1	0	0	0	0	0	0	0	0	0
(g)	0	0	0	1	0	0	0	0	0	0	0	0	0
(h)	0	1	1	1	0	0	0	0	0	0	0	0	0
(i)	1	0	0	0	1	1	1	1	1	1	1	1	1

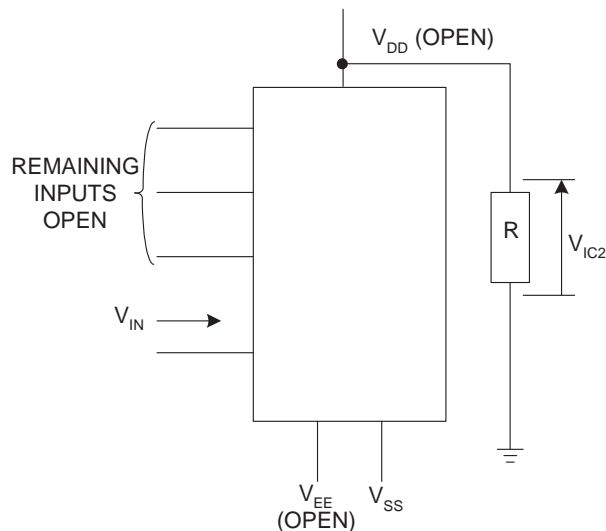
4. Channel ON Resistance shall be tested for each channel in both directions using the following input conditions:

- (a) $INH = V_{IL}$.
- (b) A, B, C = V_{IL} or V_{IH} per Truth Table to select channel under test.
- (c) I_{IN} (CHn or COM) = $100\mu A$.
- (d) R_{ON1} shall be tested with V_{IN} (CHn or COM) = 1.5V, 1.9V, 2.3V, 2.7V, 3.3V, 3.7V, 4.1V. R_{ON2} shall be tested with V_{IN} (CHn or COM) = 1.5V, 1.9V, 2.3V, 2.7V, 13.3V, 13.7V, 14.1V, 14.5V.

Channel ON Resistance shall be recorded for Channel 4 (CH4 to COM, COM to CH4) at each specified V_{IN} . Other channels may be tested go-no-go.

5. Performed as a functional test to verify for all OFF channels $I_{OFF} < 2\mu A$ with V_{IN} (CH) = V_{DD} through $1k\Omega$, COM output load resistance $R_L = 1k\Omega$.

6. Input Clamp Voltage 2 to V_{DD} , V_{IC2} , shall be tested on each input as follows:-



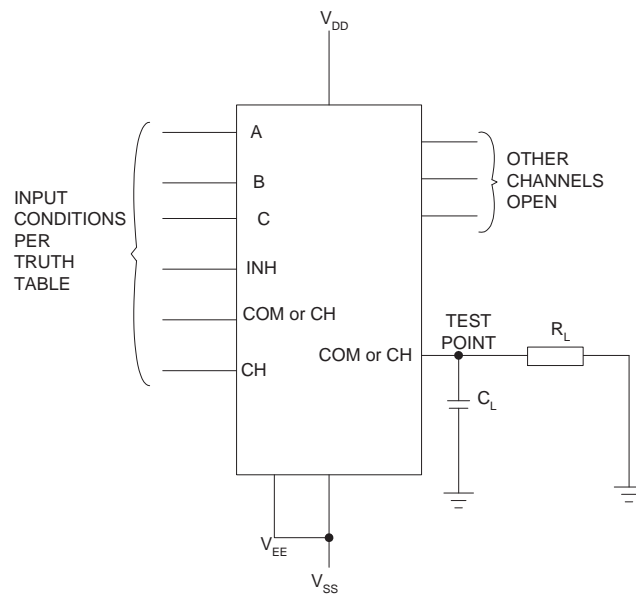
7. Guaranteed but not tested.

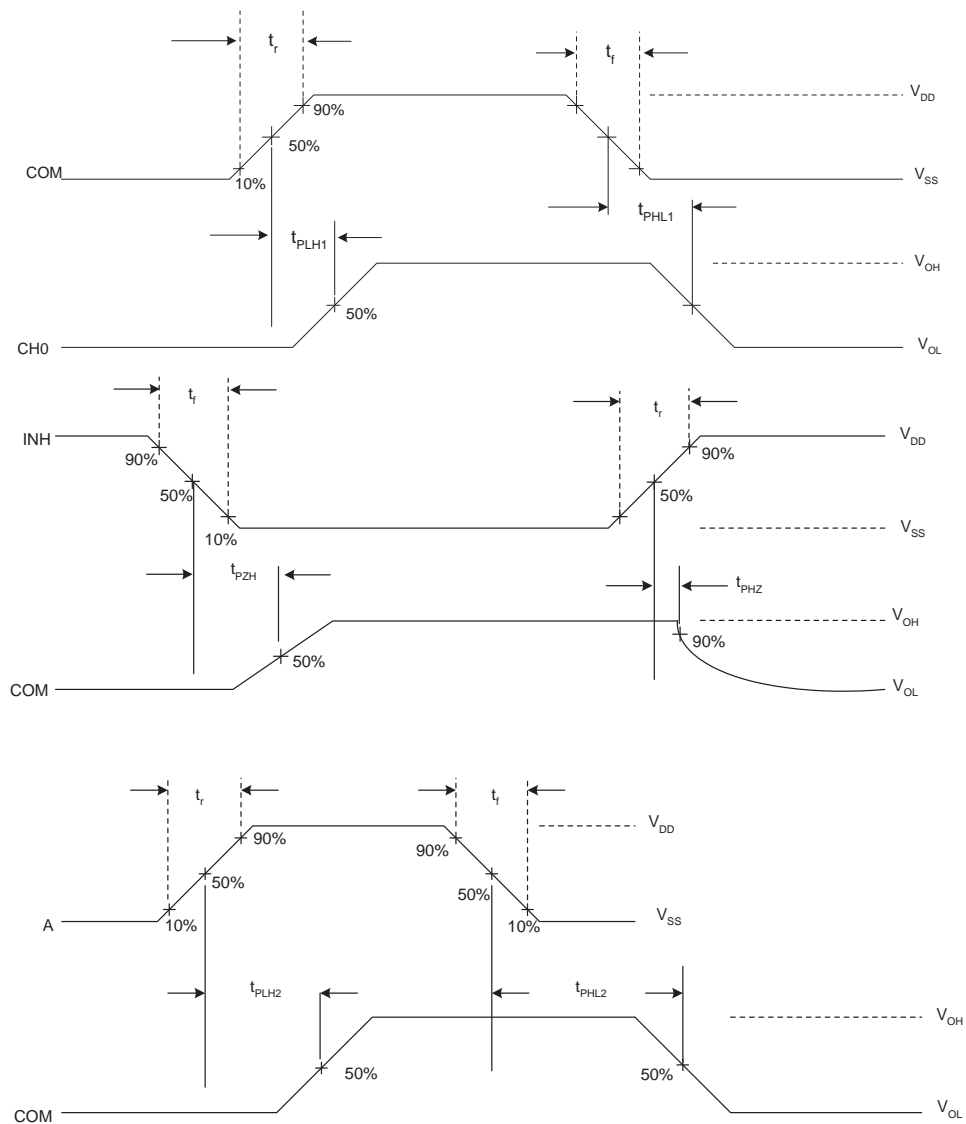
8. Read and record measurements shall be performed on a sample of 32 components with 0 failures permitted.

The pulse generator shall have the following characteristics:

$V_{GEN} = 0$ to V_{DD} ; $f = 500\text{kHz}$; t_r and $t_f \leq 15$ ns (10% to 90%); duty cycle = 50%. Output load capacitance $C_L = 50\text{pF} \pm 5\%$ including scope probe, wiring and stray capacitance without component in the test fixture. Channel bias resistance $R_L =$ as specified.

Propagation delay times shall be measured as follows:





2.4 PARAMETER DRIFT VALUES

Unless otherwise specified, the measurements shall be performed at $T_{amb} = +22 \pm 3^\circ\text{C}$.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements.

The drift values (Δ) shall not be exceeded for each characteristic specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift Value Δ	Absolute		
			Min	Max	
Quiescent Current	I_{DD}	± 75	-	500	nA
Channel ON Resistance 1, CH4 to COM, COM to CH4 Note 2	R_{ON1}	± 50	-	1050	Ω
Channel ON Resistance 2, CH4 to COM, COM to CH4 Note 2	R_{ON2}	± 15	-	280	Ω
Threshold Voltage N-Channel	V_{THN}	± 0.3	-0.7	-3	V
Threshold Voltage P-Channel	V_{THP}	± 0.3	0.7	3	V

NOTES:

1. Unless otherwise specified all inputs and outputs shall be tested for each characteristic.
2. Channel ON Resistance shall be tested at each input voltage level specified in Room Temperature Electrical Measurements in both directions for CH4 to COM only.

2.5

INTERMEDIATE AND END-POINT ELECTRICAL MEASUREMENTS

Unless otherwise specified, the measurements shall be performed at $T_{amb} = +22 \pm 3^{\circ}C$.

The test methods and test conditions shall be as per the corresponding test defined in Room Temperature Electrical Measurements .

The drift values (Δ) shall not be exceeded for each characteristic where specified. The corresponding absolute limit values for each characteristic shall not be exceeded.

Characteristics	Symbols	Limits			Units
		Drift Value Δ	Absolute		
			Min	Max	
Functional Test 1	-	-	-	-	-
Quiescent Current	I_{DD}	± 75	-	500	nA
Low Level Input Current, Control Inputs	I_{IL}	-	-	-50	nA
High Level Input Current, Control Inputs	I_{IH}	-	-	50	nA
Channel OFF Leakage Current 1, Any Channel CHn	I_{OFF1}	-	-	-100	nA
Channel OFF Leakage Current 3, All Channels Tested Together	I_{OFF3}	-	-	100	nA
Channel ON Resistance 1	R_{ON1}	± 50	-	1050	Ω
Channel ON Resistance 2	R_{ON2}	± 15	-	280	Ω
Low Level Input Voltage 1, (Noise Immunity) (Functional Test)	V_{IL1}	-	-	1.5	V
High Level Input Voltage 1, (Noise Immunity) (Functional Test)	V_{IH1}	-	3.5	-	V
Threshold Voltage N-Channel	V_{THN}	± 0.3	-0.7	-3	V
Threshold Voltage P-Channel	V_{THP}	± 0.3	0.7	3	V

NOTES:

1. Unless otherwise specified all inputs and outputs shall be tested for each characteristic.
2. The drift values (Δ) are applicable to the Operating Life test only.

2.6 HIGH TEMPERATURE REVERSE BIAS BURN-IN CONDITIONS

2.6.1 N-Channel HTRB

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T_{amb}	+125 (+0 -5)	°C
Output COM	V_{OUT}	V_{SS}	V
Inputs CHn	V_{IN}	V_{DD}	V
Inputs INH, A, B, C	V_{IN}	V_{DD}	V
Positive Supply Voltage	V_{DD}	15 (+0 -0.5)	V
Digital Negative Supply Voltage	V_{SS}	0	V
Analogue Negative Supply Voltage	V_{EE}	0	V
Duration	t	72	Hours

NOTES:

1. Input Protection Resistor = Output Load = 2kΩ min to 47kΩ max.

2.6.2 P-Channel HTRB

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T_{amb}	+125 (+0 -5)	°C
Output COM	V_{OUT}	V_{SS}	V
Inputs CHn	V_{IN}	V_{SS}	V
Inputs INH, A, B, C	V_{IN}	V_{DD}	V
Positive Supply Voltage	V_{DD}	15 (+0 -0.5)	V
Digital Negative Supply Voltage	V_{SS}	0	V
Analogue Negative Supply Voltage	V_{EE}	0	V
Duration	t	72	Hours

NOTES:

1. Input Protection Resistor = Output Load = 2kΩ min to 47kΩ max.

2.7 POWER BURN-IN CONDITIONS

Characteristics	Symbols	Test Conditions	Units
Ambient Temperature	T_{amb}	+125 (+0 -5)	°C
Output COM	V_{OUT}	V_{SS}	V
Inputs CHn	V_{IN}	V_{DD}	V
Input A	V_{IN}	V_{GEN1}	V
Input B	V_{IN}	V_{GEN2}	V
Input C	V_{IN}	V_{GEN3}	V
Input INH	V_{IN}	V_{GEN4}	V
Pulse Voltage	V_{GEN}	0V to V_{DD}	V
Pulse Frequency Square Wave	f_{GEN1} f_{GEN2} f_{GEN3} f_{GEN4}	500k 250k 125k 62.5k 50% Duty Cycle	Hz
Positive Supply Voltage	V_{DD}	15 (+0 -0.5)	V
Digital Negative Supply Voltage	V_{SS}	0	V
Analogue Negative Supply Voltage	V_{EE}	0	V

NOTES:

1. Input Protection Resistor = Output Load = 2kΩ min to 47kΩ max.

2.8 OPERATING LIFE CONDITIONS

The conditions shall be as specified for Power Burn-in.

APPENDIX 'A'

AGREED DEVIATIONS FOR STMICROELECTRONICS (F)

ITEMS AFFECTED	DESCRIPTION OF DEVIATIONS
<p>Deviations from Screening Tests - Chart F3</p>	<p>External Visual Inspection: The criteria applicable to chip outs are those described in MIL-STD-883, Test Method 2009, Paras 3.3.6(b) and 3.3.7(a).</p> <p>High Temperature Reverse Bias Burn-in: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.</p> <p>Power Burn-in test is performed using STMicroelectronics Specification Ref: 0019255.</p>
<p>Deviations from Qualification and Periodic Tests - Chart F4</p>	<p>External Visual Inspection: The criteria applicable to chip outs are those described in MIL-STD-883, Test Method 2009, Paras 3.3.6(b) and 3.3.7(a).</p> <p>Operating Life: The temperature limits of MIL-STD-883, Para. 4.5.8(c) may be used.</p>
<p>Deviations from High and Low Temperatures Electrical Measurements</p>	<p>High and Low Temperatures Electrical Measurements may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes High and Low Temperatures Electrical Measurements per the Detail Specification.</p> <p>A summary of the pilot lot testing shall be provided if required by the Purchase Order.</p>
<p>Deviations from Room Temperature Electrical Measurements</p>	<p>All AC characteristics (Capacitance and Timings) may be considered guaranteed but not tested if successful pilot lot testing has been performed on the wafer lot which includes AC characteristic measurements per the Detail Specification.</p> <p>A summary of the pilot lot testing shall be provided if required by the Purchase Order.</p>